



TPS54528

SLVSAY4C -JULY 2011-REVISED MARCH 2014

TPS54528 4.5-V To 18-V Input, 5-A Synchronous Step-Down Converter With Eco-Mode™

Features

- D-CAP2™ Mode Enables Fast Transient Response
- Low Output Ripple and Allows Ceramic Output Capacitor
- Wide V_{IN} Input Voltage Range: 4.5 V to 18 V
- Output Voltage Range: 0.76 V to 6 V
- Highly Efficient Integrated FETs Optimized for Lower Duty Cycle Applications $-65 \text{ m}\Omega$ (High Side) and 36 m Ω (Low Side)
- High Efficiency, less than 10 µA at shutdown
- High Initial Bandgap Reference Accuracy
- Adjustable Soft Start
- Pre-Biased Soft Start
- 650-kHz Switching Frequency (f_{SW})
- Cycle By Cycle Over Current Limit
- Auto-Skip Eco-mode™ for High Efficiency at Light Load

2 Applications

- Wide Range of Applications for Low Voltage System
 - Digital TV Power Supply
 - High Definition Blu-ray Disc™ Players
 - **Networking Home Terminal**
 - Digital Set Top Box (STB)

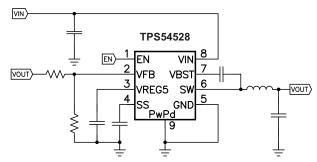
3 Description

The TPS54528 is an adaptive on-time D-CAP2™ mode synchronous buck converter. The TPS54528 enables system designers to complete the suite of various end-equipment power bus regulators with a cost effective, low component count, low standby current solution. The main control loop for the TPS54528 uses the D-CAP2™ mode control that provides a fast transient response with no external compensation components. The adaptive on-time control supports seamless transition between PWM mode at higher load conditions and Eco-mode™ operation at light loads. Eco-mode™ allows the TPS54528 to maintain high efficiency during lighter load conditions. The TPS54528 also has a proprietary circuit that enables the device to adopt to both low equivalent series resistance (ESR) output capacitors, such as POSCAP or SP-CAP, and ultra-low ESR ceramic capacitors. The device operates from 4.5-V to 18-V VIN input. The output voltage can be programmed between 0.76 V and 6 V. The device also features an adjustable soft start time. The TPS54528 is available in the 8-terminal DDA package, and designed to operate from -40°C to 85°C.

Device Information

ORDER NUMBER	PACKAGE	BODY SIZE
TPS54528DDA	HSOP (8)	4,89 mm × 3,9 mm

Simplified Schematic



1.05-V, Load Transient Response

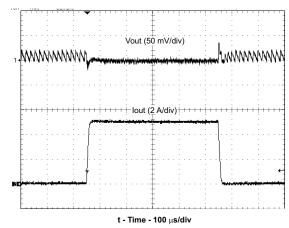




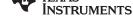
Table of Contents

2 Applications 1 8.4 Device Functional Modes 3 Description 1 9 Applications and Implementation 4 Simplified Schematic 1 9.1 Application Information 5 Payision History 2 9.2 Typical Application	
3 Description	12
4 Simplified Schematic 1 9.1 Application Information	
0.2 Typical Application	12
5 Revision History	12
6 Terminal Configuration and Functions	15
7 Specifications4 11 Layout	15
7.1 Absolute Maximum Ratings	15
7.2 Handling Ratings	16
7.3 Recommended Operating Conditions 4 11.3 Thermal Information	17
7.4 Thermal Information	t 18
7.5 Electrical Characteristics	18
7.6 Timing Requirements - On-Time Timer Control 6 12.2 Trademarks	18
7.7 Typical Characteristics 6 12.3 Electrostatic Discharge Caution	18
8 Detailed Description 9 12.4 Glossary	18
8.1 Overview	
8.2 Functional Block Diagram 9	IC

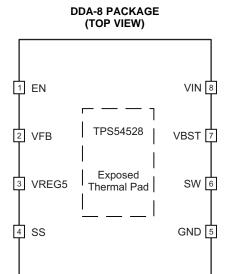
5 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision B (May 2012) to Revision C	Page
Formatted data sheet to meet new template requirements	1
Added Table of Contents, and moved Revision History to page 2.	3
Moved ABS Max, Handling Ratings, ROC, Thermal Info, and Electrical Characteristics tables to the new "Specifications" section.	4
Added Maximum Power Dissipation graph	8
Added "Power Supply Recommendations" section	15
Added "Device and Documentation Support" section	18
Changes from Revision A (January 2012) to Revision B	Page
Changed t _{OFF(MIN)} From: 310 ns To: 330 ns	6
Changes from Original (July 2011) to Revision A	Page
Added CONDITIONS statement at the Typical Characteristics section heading	6
• Changed 2-μA to 6μA in Soft Start and Pre-Biased Soft Start subsection and denominator in equation 2	g



6 Terminal Configuration and Functions



Terminal Functions

TERMINAL		DESCRIPTION
NAME	NO.	DESCRIPTION
EN	1	Enable input control. EN is active high and must be pulled up to enable the device.
VFB	2	Converter feedback input. Connect to output voltage with feedback resistor divider.
VREG5	3	$5.5\ V$ power supply output. A capacitor (typical 1 $\mu\text{F})$ should be connected to GND. VREG5 is not active when EN is low.
SS	4	Soft-start control. An external capacitor should be connected to GND.
GND	5	Ground terminal. Power ground return for switching circuit. Connect sensitive SS and VFB returns to GND at a single point.
SW	6	Switch node connection between high-side NFET and low-side NFET.
VBST	7	Supply input for the high-side FET gate drive circuit. Connect 0.1µF capacitor between VBST and SW terminals. An internal diode is connected between VREG5 and VBST.
VIN	8	Input voltage supply terminal.
Exposed Thermal Pad	Back side	Thermal pad of the package. Must be soldered to achieve appropriate dissipation. Must be connected to GND.

7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)

		VA	VALUE		
		MIN	MAX	UNIT	
	VIN, EN	-0.3	20		
	VBST	-0.3	26		
	VBST (10 ns transient)	-0.3	28		
nput voltage range	VBST (vs SW)	-0.3	6.5	V	
	VFB, SS	-0.3	6.5		
	SW	-2	20		
	SW (10 ns transient)	-3	22		
Output valta sa sasas	VREG5	-0.3	6.5	.,	
Output voltage range GND -0.3		0.3	V		
Voltage from GND to therma	al pad, V _{diff}	-0.2	0.2	V	
Operating junction temperat	ure, T _J	-40	150	°C	

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 Handling Ratings

		MIN	MAX	UNIT
T _{stg}	Storage temperature range	-55	150	ů
Clastrostatic discharge	Human Body Model (HBM)		2	kV
Electrostatic discharge	Charged Device Model (CDM)		500	V

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{IN}	Supply input voltage		4.5	18	V
		VBST	-0.1	24	
		VBST (10 ns transient)	-0.1	27	
		VBST(vs SW)	-0.1	5.7	
		SS	-0.1	5.7	
VI	Input voltage	EN	-0.1	18	V
		VFB	-0.1	5.5	
		SW	-1.8	18	
		SW (10 ns transient)	-3	21	
		GND	-0.1	0.1	
Vo	Output voltage	VREG5	-0.1	5.7	V
Io	Output Current	I _{VREG5}	0	5	mA
T _A	Operating free-air temperature	-40	85	°C	
TJ	Operating junction temperature				



7.4 Thermal Information

	THERMAL METRIC ⁽¹⁾	TPS54528	UNIT
	I HERMAL METRIC	DDA (8)	UNIT
θ_{JA}	Junction-to-ambient thermal resistance	43.5	
θ_{JCtop}	Junction-to-case (top) thermal resistance	49.4	
θ_{JB}	Junction-to-board thermal resistance	25.6	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	7.4	*C/VV
ψ_{JB}	Junction-to-board characterization parameter	25.5	
θ_{JCbot}	Junction-to-case (bottom) thermal resistance	5.2	

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

7.5 Electrical Characteristics

over operating free-air temperature range, V_{IN} = 12 V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY	CURRENT					
I _{VIN}	Operating - non-switching supply current	Operating - non-switching supply current V_{IN} current, $T_A = 25$ °C, $EN = 5$ V, $V_{FB} = 0.8$ V				μΑ
I _{VINSDN}	Shutdown supply current	V _{IN} current, T _A = 25°C, EN = 0 V		3.6	10	μΑ
LOGIC T	HRESHOLD		·		·	
\/	EN high-level input voltage	EN	1.6			V
V_{EN}	EN low-level input voltage	EN			0.6	V
V _{FB} VOL	TAGE AND DISCHARGE RESISTANCE					
		$T_A = 25$ °C, $V_O = 1.05$ V, $I_O = 10$ mA, Ecomode TM operation		771		mV
V_{FBTH}	V _{FB} threshold voltage	$T_A = 25$ °C, $V_O = 1.05$ V, continuous mode operation	757	765	773	mV
		T_A = -40 to 85°C, V_O = 1.05 V, continuous mode operation ⁽¹⁾	751	765	779	mV
I _{VFB}	V _{FB} input current	V _{FB} = 0.8 V, T _A = 25°C		0	±0.15	μΑ
V _{REG5} OL	JTPUT					
V_{VREG5}	V _{REG5} output voltage	T _A = 25°C, 6.0 V < V _{IN} < 18 V, 0 < I _{VREG5} < 5 mA	5.2	5.5	5.7	V
V_{LN5}	Line regulation	6 V < V _{IN} < 18 V, I _{VREG5} = 5 mA			25	mV
V_{LD5}	Load regulation	0 mA < I _{VREG5} < 5 mA			100	mV
I _{VREG5}	Output current	V _{IN} = 6 V, V _{REG5} = 4.0 V, T _A = 25°C		60		mA
MOSFET						
D	High side switch resistance	25°C, V _{BST} - SW = 5.5 V		65		mΩ
R _{DS(on)}	Low side switch resistance	25°C		36		mΩ
CURREN	T LIMIT					
I _{ocl}	Current limit	L out = 1.5 µH ⁽¹⁾	5.6	6.4	7.9	Α
THERMA	LSHUTDOWN					
T	Thermal shutdown throubald	Shutdown temperature ⁽¹⁾		165		۰.۵
T _{SDN}	Thermal shutdown threshold	Hysteresis ⁽¹⁾	35			°C

⁽¹⁾ Not production tested.



Electrical Characteristics (continued)

over operating free-air temperature range, V_{IN} = 12 V (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT			
SOFT START									
I _{SS}	SS charge current	V _{SS} = 1 V	4.2	6	7.8	μΑ			
	SS discharge current	V _{SS} = 0.5 V	0.1	0.2		mA			
UVLO									
UVLO	UVLO threshold	Wake up V _{REG5} voltage	3.45	3.75	4.05	V			
	OVEO triresnoid	Hysteresis V _{REG5} voltage	0.19	0.32	0.45	V			

7.6 Timing Requirements - On-Time Timer Control

			MIN	TYP	MAX	UNIT
t _{ON}	On time	$V_{IN} = 12 \text{ V}, V_{O} = 1.05 \text{ V}$		150		ns
t _{OFF(MIN)}	Minimum off time	$T_A = 25^{\circ}C, V_{FB} = 0.7 V$		260	330	ns

7.7 Typical Characteristics

VIN = 12 V, $T_A = 25$ °C (unless otherwise noted).

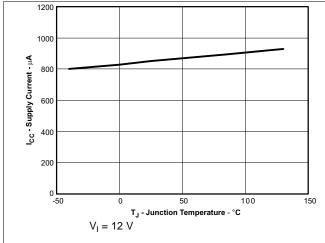


Figure 1. VIN Current vs Junction Temperature

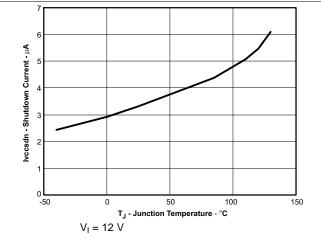
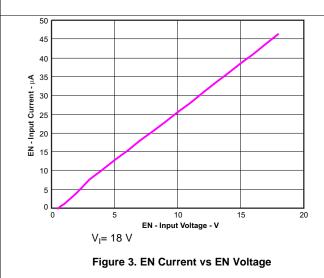


Figure 2. VIN Shutdown Current vs Junction Temperature



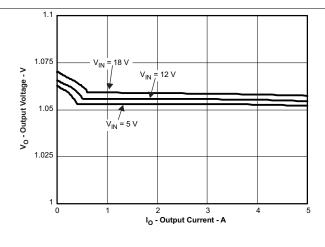


Figure 4. 1.05-V Output Voltage vs Output Current

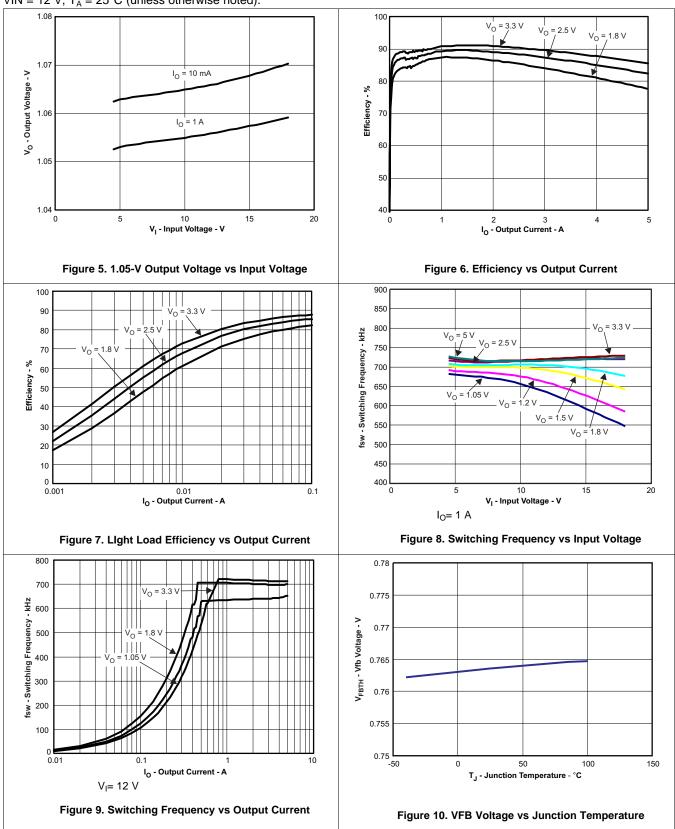
6

Copyright © 2011–2014, Texas Instruments Incorporated



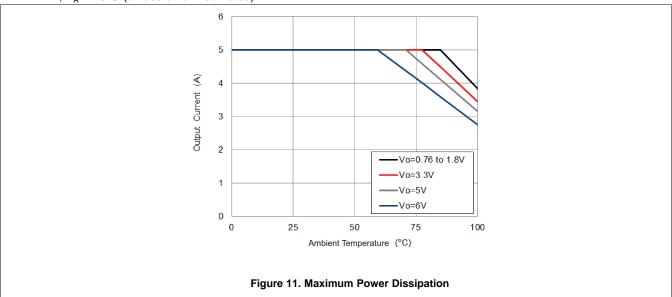
Typical Characteristics (continued)

VIN = 12 V, T_A = 25°C (unless otherwise noted).



Typical Characteristics (continued)

 $VIN = 12 \text{ V}, T_A = 25^{\circ}\text{C}$ (unless otherwise noted).



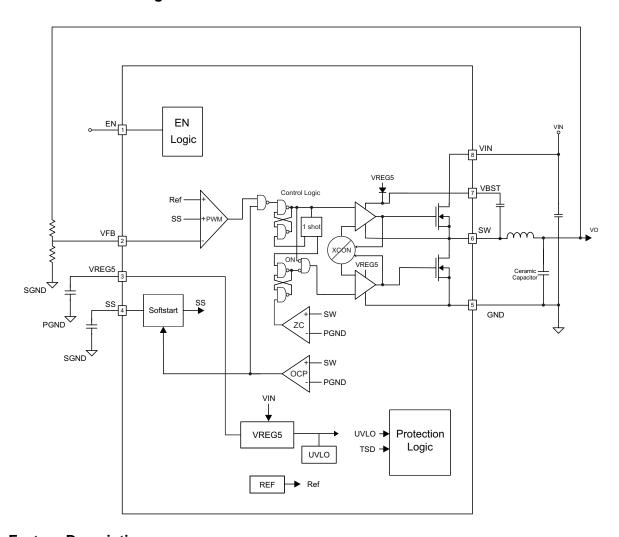


8 Detailed Description

8.1 Overview

The TPS54528 is a 5-A synchronous step-down (buck) converter with two integrated N-channel MOSFETs. It operates using D-CAP2[™] mode control. The fast transient response of D-CAP2[™] control reduces the output capacitance required to meet a specific level of performance. Proprietary internal circuitry allows the use of low ESR output capacitors including ceramic and special polymer types.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Soft Start And Pre-Biased Soft Start

The soft start function is adjustable. When the EN terminal becomes high, 6μ A current begins charging the capacitor which is connected from the SS terminal to GND. Smooth control of the output voltage is maintained during start up. The equation for the slow start time is shown in Equation 1. VFB voltage is 0.765 V and SS terminal source current is 6μ A.

$$t_{SS}(ms) = \frac{C6(nF) \times V_{FB} \times 1.1}{I_{SS}(\mu A)} = \frac{C6(nF) \times 0.765 \times 1.1}{6}$$
(1)

Copyright © 2011–2014, Texas Instruments Incorporated

9

Feature Description (continued)

The TPS54528 contains a unique circuit to prevent current from being pulled from the output during startup if the output is pre-biased. When the soft-start commands a voltage higher than the pre-bias level (internal soft start becomes greater than feedback voltage V_{FB}), the controller slowly activates synchronous rectification by starting the first low side FET gate driver pulses with a narrow on-time. It then increments that on-time on a cycle-bycycle basis until it coincides with the time dictated by (1-D), where D is the duty cycle of the converter. This scheme prevents the initial sinking of the pre-bias output, and ensure that the out voltage (V_O) starts and ramps up smoothly into regulation and the control loop is given time to transition from pre-biased start-up to normal mode operation.

8.3.2 Current Protection

The output overcurrent protection (OCP) is implemented using a cycle-by-cycle valley detect control circuit. The switch current is monitored by measuring the low-side FET switch voltage between the SW terminal and GND. This voltage is proportional to the switch current. To improve accuracy, the voltage sensing is temperature compensated.

During the on time of the high-side FET switch, the switch current increases at a linear rate determined by V_{IN} , V_{OUT} , the on-time and the output inductor value. During the on time of the low-side FET switch, this current decreases linearly. The average value of the switch current is the load current lout. The TPS54528 constantly monitors the low-side FET switch voltage, which is proportional to the switch current, during the low-side on-time. If the measured voltage is above the voltage proportional to the current limit, an internal counter is incremented per each SW cycle and the converter maintains the low-side switch on until the measured voltage is below the voltage corresponding to the current limit at which time the switching cycle is terminated and a new switching cycle begins. In subsequent switching cycles, the on-time is set to a fixed value and the current is monitored in the same manner. If the over current condition exists for 7 consecutive switching cycles, the internal OCL threshold is set to a lower level, reducing the available output current. When a switching cycle occurs where the switch current is not above the lower OCL threshold, the counter is reset and the OCL limit is returned to the higher value.

There are some important considerations for this type of over-current protection. The peak current is the average load current plus one half of the peak-to-peak inductor current. The valley current is the average load current minus one half of the peak-to-peak inductor current. Since the valley current is used to detect the overcurrent threshold, the load current is higher than the over-current threshold. Also, when the current is being limited, the output voltage tends to fall as the demanded load current may be higher than the current available from the converter. When the over current condition is removed, the output voltage will return to the regulated value. This protection is non-latching.

8.3.3 UVLO Protection

Undervoltage lock out protection (UVLO) monitors the voltage of the V_{REG5} terminal. When the V_{REG5} voltage is lower than UVLO threshold voltage, the TPS54528 is shut off. This protection is non-latching.

8.3.4 Thermal Shutdown

TPS54528 monitors the temperature of itself. If the temperature exceeds the threshold value (typically 165°C), the device is shut off. This is non-latch protection.

8.4 Device Functional Modes

8.4.1 PWM Operation

The main control loop of the TPS54528 is an adaptive on-time pulse width modulation (PWM) controller that supports a proprietary D-CAP2™ mode control. D-CAP2™ mode control combines constant on-time control with an internal compensation circuit for pseudo-fixed frequency and low external component count configuration with both low ESR and ceramic output capacitors. It is stable even with virtually no ripple at the output.



Device Functional Modes (continued)

At the beginning of each cycle, the high-side MOSFET is turned on. This MOSFET is turned off after internal one shot timer expires. This one shot is set by the converter input voltage, VIN, and the output voltage, VO, to maintain a pseudo-fixed frequency over the input voltage range, hence it is called adaptive on-time control. The one-shot timer is reset and the high-side MOSFET is turned on again when the feedback voltage falls below the reference voltage. An internal ramp is added to reference voltage to simulate output ripple, eliminating the need for ESR induced output ripple from D-CAP2TM mode control.

8.4.2 PWM Frequency And Adaptive On-Time Control

TPS54528 uses an adaptive on-time control scheme and does not have a dedicated on board oscillator. The TPS54528 runs with a pseudo-constant frequency of 700 kHz by using the input voltage and output voltage to set the on-time one-shot timer. The on-time is inversely proportional to the input voltage and proportional to the output voltage; therefore, when the duty ratio is VOUT/VIN, the frequency is constant.

8.4.3 Auto-Skip Eco-Mode™ Control

The TPS54528 is designed with Auto-Skip Eco-modeTM to increase light load efficiency. As the output current decreases from heavy load condition, the inductor current is also reduced and eventually comes to point that its rippled valley touches zero level, which is the boundary between continuous conduction and discontinuous conduction modes. The rectifying MOSFET is turned off when its zero inductor current is detected. As the load current further decreases the converter run into discontinuous conduction mode. The on-time is kept almost the same as is was in the continuous conduction mode so that it takes longer time to discharge the output capacitor with smaller load current to the level of the reference voltage. The transition point to the light load operation $I_{OUT(LL)}$ current can be calculated in Equation 2

$$I_{OUT(LL)} = \frac{1}{2 \cdot L \cdot fsw} \cdot \frac{\left(V_{IN} - V_{OUT}\right) \cdot V_{OUT}}{V_{IN}} \tag{2}$$

Copyright © 2011–2014, Texas Instruments Incorporated

11

9 Applications and Implementation

9.1 Application Information

The TPS54528 is designed to provide up to a 2-A output current from an input voltage source ranging from 4.5 V to 18 V. The output voltage is configurable from 0.76 V to 6 V. A simplified design procedure for a 1.05-V output is shown below .

9.2 Typical Application

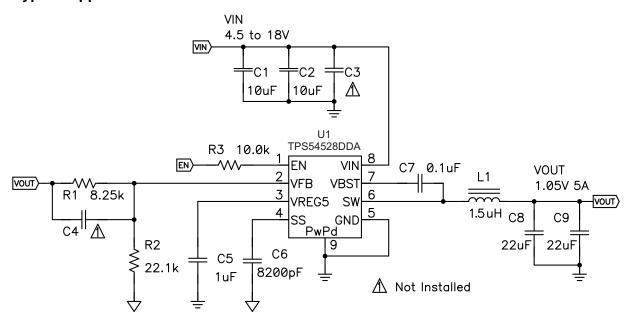


Figure 12. 5-A Synchronous Step-Down (Buck) Converter

9.2.1 Design Requirements

Figure 12 shows the schematic of the design example.

To begin the design process, the user must know a few application parameters:

- Input voltage range
- Output voltage
- Output current
- Output voltage ripple
- Input voltage ripple

9.2.2 Detailed Design Procedure

9.2.2.1 Output Voltage Resistors Selection

The output voltage is set with a resistor divider from the output node to the VFB terminal. It is recommended to use 1% tolerance or better divider resistors. Start by using Equation 3 to calculate V_{OUT} .

To improve efficiency at light loads consider using larger value resistors, high resistance is more susceptible to noise, and the voltage errors from the VFB input current are more noticeable.

$$V_{OUT} = 0.765 \times \left(1 + \frac{R1}{R2}\right)$$
 (3)

12



Typical Application (continued)

9.2.2.2 Output Filter Selection

The output filter used with the TPS54528 is an LC circuit. This LC filter has double pole at:

$$F_{p} = \frac{1}{2\pi \sqrt{L_{OUT} \times C_{OUT}}}$$
(4)

At low frequencies, the overall loop gain is set by the output set-point resistor divider network and the internal gain of the TPS54528. The low frequency phase is 180 degrees. At the output filter pole frequency, the gain rolls off at a −40 dB per decade rate and the phase drops rapidly. D-CAP2™ introduces a high frequency zero that reduces the gain roll off to −20 dB per decade and increases the phase to 90 degrees one decade above the zero frequency. The inductor and capacitor selected for the output filter must be selected so that the double pole of Equation 4 is located below the high frequency zero but close enough that the phase boost provided be the high frequency zero provides adequate phase margin for a stable circuit. To meet this requirement use the values recommended in Table 1.

C4 (pF)⁽¹⁾ Output Voltage (V) R1 (kΩ) R2 (kΩ) L1 (µH) $C8 + C9 (\mu F)$ 1 6.81 22.1 1.0 - 1.5 22 - 68 1.05 8.25 22.1 1.0 - 1.5 22 - 68 1.2 12.7 1.0 - 1.5 22 - 68 22.1 1.5 21.5 22.1 1.5 22 - 68 1.8 30.1 22.1 5 - 22 1.5 22 - 68 5 - 22 2.2 2.5 49.9 22.1 22 - 68 3.3 73.2 22.1 5 - 22 2.2 22 - 68 5 124 22.1 5 - 22 3.3 22 - 68

Table 1. Recommended Component Values

(1) Optional

Since the DC gain is dependent on the output voltage, the required inductor value increases as the output voltage increases. For higher output voltages at or above 1.8 V, additional phase boost can be achieved by adding a feed forward capacitor (C4) in parallel with R1

The inductor peak-to-peak ripple current, peak current and RMS current are calculated using Equation 5, Equation 6 and Equation 7. The inductor saturation current rating must be greater than the calculated peak current and the RMS or heating current rating must be greater than the calculated RMS current. Use 700 kHz for f_{SW} .

Use 650 kHz for f_{SW}. Make sure the chosen inductor is rated for the peak current of Equation 6 and the RMS current of Equation 7.

$$I_{IPP} = \frac{V_{OUT}}{V_{IN(max)}} \times \frac{V_{IN(max)} - V_{OUT}}{L_{O} \times f_{SW}}$$
(5)

$$I_{\text{lpeak}} = I_{\text{O}} + \frac{I_{\text{lpp}}}{2} \tag{6}$$

$$I_{Lo(RMS)} = \sqrt{I_O^2 + \frac{1}{12} I_{IPP}^2}$$
 (7)

For this design example, the calculated peak current is 5.51 A and the calculated RMS current is 5.01 A. The inductor used is a TDK SPM6530-1R5M100 with a peak current rating of 11.5 A and an RMS current rating of 11 A.

The capacitor value and ESR determines the amount of output voltage ripple. The TPS54528 is intended for use with ceramic or other low ESR capacitors. Recommended values range from $22\mu\text{F}$ to $68\mu\text{F}$. Use Equation 8 to determine the required RMS current rating for the output capacitor.

$$I_{\text{Co(RMS)}} = \frac{V_{\text{OUT}} \times (V_{\text{IN}} - V_{\text{OUT}})}{\sqrt{12} \times V_{\text{IN}} \times L_{\text{O}} \times f_{\text{SW}}}$$
(8)

Copyright © 2011–2014, Texas Instruments Incorporated

13

For this design two TDK C3216X5R0J226M 22 μ F output capacitors are used. The typical ESR is 2 m Ω each. The calculated RMS current is 0.29 A and each output capacitor is rated for 4A.

9.2.2.3 Input Capacitor Selection

The TPS54528 requires an input decoupling capacitor and a bulk capacitor is needed depending on the application. A ceramic capacitor over 10 μ F is recommended for the decoupling capacitor. An additional 0.1 μ F capacitor (C3) from terminal 8 to ground is optional to provide additional high frequency filtering. The capacitor voltage rating needs to be greater than the maximum input voltage.

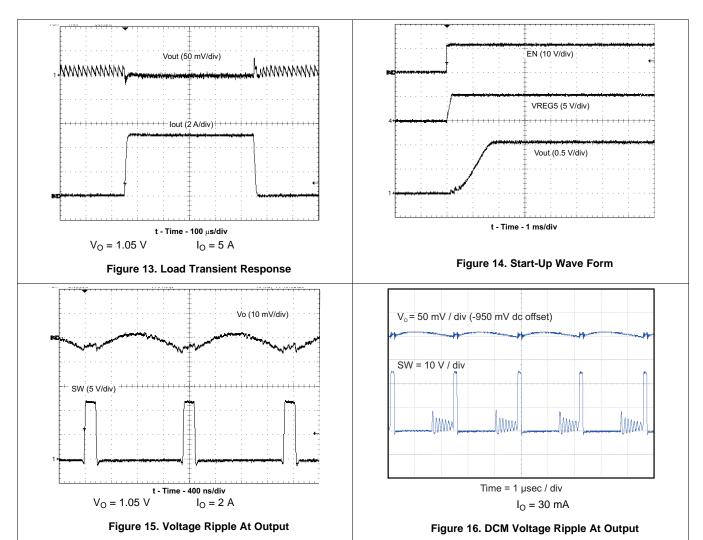
9.2.2.4 Bootstrap Capacitor Selection

A 0.1 μ F. ceramic capacitor must be connected between the VBST to SW terminal for proper operation. It is recommended to use a ceramic capacitor.

9.2.2.5 Vreg5 Capacitor Selection

A 1-µF. ceramic capacitor must be connected between the VREG5 to GND terminal for proper operation. It is recommended to use a ceramic capacitor.

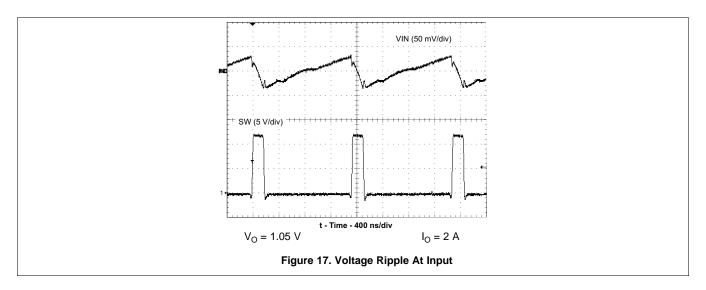
9.2.3 Application Performance Curves



14

Copyright © 2011–2014, Texas Instruments Incorporated





10 Power Supply Recommendations

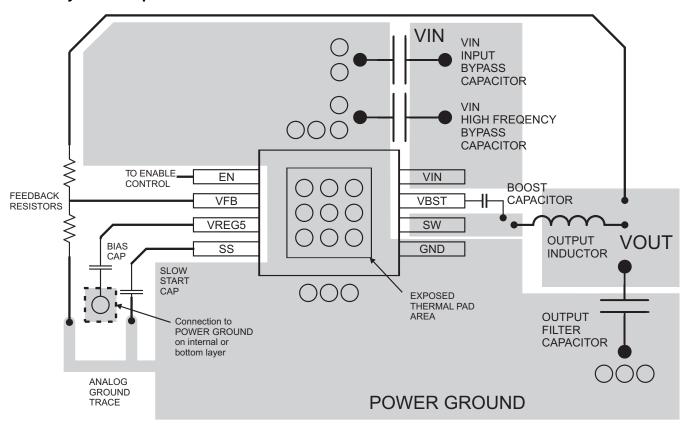
The input voltage range is from 4.5V to 18V. The input power supply and the input capacitors should be located as close to the device as possible to minimize the impedance of the power-supply line.

11 Layout

11.1 Layout Guidelines

- 1. The TPS54528 can supply large load currents up to 5 A, so heat dissipation may be a concern. The top side area adjacent to the TPS54528 should be filled with ground as much as possible to dissipate heat.
- 2. The bottom side area directly below the IC should a dedicated ground area. It should be directly connected to the thermal pad of the device using vias as shown. The ground area should be as large as practical. Additional internal layers can be dedicated as ground planes and connected to the vias as well.
- 3. Keep the input switching current loop as small as possible.
- 4. Keep the SW node as physically small and short as possible to minimize parasitic capacitance and inductance and to minimize radiated emissions. Kelvin connections should be brought from the output to the feedback terminal of the device.
- 5. Keep analog and non-switching components away from switching components.
- 6. Make a single point connection from the signal ground to power ground.
- 7. Do not allow switching current to flow under the device.
- 8. Keep the pattern lines for VIN and PGND broad.
- 9. Exposed pad of device must be connected to PGND with solder.
- 10. VREG5 capacitor should be placed near the device, and connected PGND.
- 11. Output capacitor should be connected to a broad pattern of the PGND.
- 12. Voltage feedback loop should be as short as possible, and preferably with ground shield.
- 13. Lower resistor of the voltage divider which is connected to the VFB terminal should be tied to SGND.
- 14. Providing sufficient via is preferable for VIN, SW and PGND connection.
- 15. PCB pattern for VIN, SW, and PGND should be as broad as possible.
- 16. VIN Capacitor should be placed as near as possible to the device.

11.2 Layout Example



VIA to Ground Plane

16



11.3 Thermal Information

This 8-terminal DDA package incorporates an exposed thermal pad that is designed to be directly connected to an external heatsink. The thermal pad must be soldered directly to the printed board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the exposed thermal pad and how to use the advantage of its heat dissipating abilities, see the Technical Brief, *PowerPAD™ Thermally Enhanced Package*, Texas Instruments Literature No. SLMA002 and Application Brief, *PowerPAD™ Made Easy*, Texas Instruments Literature No. SLMA004.

The exposed thermal pad dimensions for this package are shown in the following illustration.

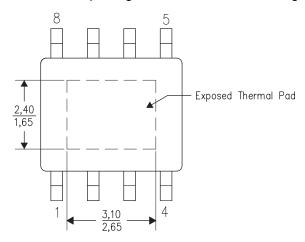


Figure 18. Thermal Pad Dimensions

12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

D-CAP2TM Frequency Response Model, SLVA546

TPS54528EVM-052, 5-A, SWIFT™ Regulator Evaluation Module, SLVU480

12.2 Trademarks

D-CAP2, Eco-mode are trademarks of Texas Instruments. Blu-ray Disc is a trademark of Blu-ray Disc Association.

12.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



PACKAGE OPTION ADDENDUM

1-Mar-2017

PACKAGING INFORMATION

Orderable Device	Status	Package Type	•	Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
TPS54528DDA	ACTIVE	SO PowerPAD	DDA	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-2-260C-1 YEAR	-40 to 85	54528	Samples
TPS54528DDAR	ACTIVE	SO PowerPAD	DDA	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-2-260C-1 YEAR	-40 to 85	54528	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.



PACKAGE OPTION ADDENDUM

1-Mar-2017

In no event shall TI's liabilit	ty arising out of such information	exceed the total purchase price	ce of the TI part(s) at issue in th	is document sold by TI to Cu	stomer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com 24-Feb-2014

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS54528DDAR	SO Power PAD	DDA	8	2500	330.0	12.8	6.4	5.2	2.1	8.0	12.0	Q1

www.ti.com 24-Feb-2014



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
TPS54528DDAR	SO PowerPAD	DDA	8	2500	366.0	364.0	50.0	

DDA (R-PDSO-G8)

PowerPAD ™ PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com http://www.ti.com.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- F. This package complies to JEDEC MS-012 variation BA

PowerPAD is a trademark of Texas Instruments.



DDA (R-PDSO-G8)

PowerPAD™ PLASTIC SMALL OUTLINE

THERMAL INFORMATION

This PowerPAD package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Exposed Thermal Pad Dimensions

4206322-6/L 05/12

NOTE: A. All linear dimensions are in millimeters



DDA (R-PDSO-G8)

PowerPAD™ PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.
- F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

PowerPAD is a trademark of Texas Instruments.



IMPORTANT NOTICE FOR TI DESIGN INFORMATION AND RESOURCES

Texas Instruments Incorporated ('TI") technical, application or other design advice, services or information, including, but not limited to, reference designs and materials relating to evaluation modules, (collectively, "TI Resources") are intended to assist designers who are developing applications that incorporate TI products; by downloading, accessing or using any particular TI Resource in any way, you (individually or, if you are acting on behalf of a company, your company) agree to use it solely for this purpose and subject to the terms of this Notice.

TI's provision of TI Resources does not expand or otherwise alter TI's applicable published warranties or warranty disclaimers for TI products, and no additional obligations or liabilities arise from TI providing such TI Resources. TI reserves the right to make corrections, enhancements, improvements and other changes to its TI Resources.

You understand and agree that you remain responsible for using your independent analysis, evaluation and judgment in designing your applications and that you have full and exclusive responsibility to assure the safety of your applications and compliance of your applications (and of all TI products used in or for your applications) with all applicable regulations, laws and other applicable requirements. You represent that, with respect to your applications, you have all the necessary expertise to create and implement safeguards that (1) anticipate dangerous consequences of failures, (2) monitor failures and their consequences, and (3) lessen the likelihood of failures that might cause harm and take appropriate actions. You agree that prior to using or distributing any applications that include TI products, you will thoroughly test such applications and the functionality of such TI products as used in such applications. TI has not conducted any testing other than that specifically described in the published documentation for a particular TI Resource.

You are authorized to use, copy and modify any individual TI Resource only in connection with the development of applications that include the TI product(s) identified in such TI Resource. NO OTHER LICENSE, EXPRESS OR IMPLIED, BY ESTOPPEL OR OTHERWISE TO ANY OTHER TI INTELLECTUAL PROPERTY RIGHT, AND NO LICENSE TO ANY TECHNOLOGY OR INTELLECTUAL PROPERTY RIGHT OF TI OR ANY THIRD PARTY IS GRANTED HEREIN, including but not limited to any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information regarding or referencing third-party products or services does not constitute a license to use such products or services, or a warranty or endorsement thereof. Use of TI Resources may require a license from a third party under the patents or other intellectual property of TI.

TI RESOURCES ARE PROVIDED "AS IS" AND WITH ALL FAULTS. TI DISCLAIMS ALL OTHER WARRANTIES OR REPRESENTATIONS, EXPRESS OR IMPLIED, REGARDING TI RESOURCES OR USE THEREOF, INCLUDING BUT NOT LIMITED TO ACCURACY OR COMPLETENESS, TITLE, ANY EPIDEMIC FAILURE WARRANTY AND ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, AND NON-INFRINGEMENT OF ANY THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

TI SHALL NOT BE LIABLE FOR AND SHALL NOT DEFEND OR INDEMNIFY YOU AGAINST ANY CLAIM, INCLUDING BUT NOT LIMITED TO ANY INFRINGEMENT CLAIM THAT RELATES TO OR IS BASED ON ANY COMBINATION OF PRODUCTS EVEN IF DESCRIBED IN TI RESOURCES OR OTHERWISE. IN NO EVENT SHALL TI BE LIABLE FOR ANY ACTUAL, DIRECT, SPECIAL, COLLATERAL, INDIRECT, PUNITIVE, INCIDENTAL, CONSEQUENTIAL OR EXEMPLARY DAMAGES IN CONNECTION WITH OR ARISING OUT OF TI RESOURCES OR USE THEREOF, AND REGARDLESS OF WHETHER TI HAS BEEN ADVISED OF THE POSSIBILITY OF SUCH DAMAGES.

You agree to fully indemnify TI and its representatives against any damages, costs, losses, and/or liabilities arising out of your non-compliance with the terms and provisions of this Notice.

This Notice applies to TI Resources. Additional terms apply to the use and purchase of certain types of materials, TI products and services. These include; without limitation, TI's standard terms for semiconductor products http://www.ti.com/sc/docs/stdterms.htm), evaluation modules, and samples (http://www.ti.com/sc/docs/sampterms.htm).

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2017, Texas Instruments Incorporated